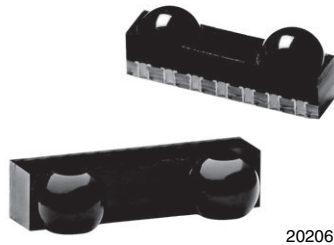


Infrared Transceiver, 9.6 kbit/s to 115.2 kbit/s (SIR)



20206


RoHS
COMPLIANT

FEATURES

- Compliant with the IrDA physical layer IrPHY 1.4 (low power specification, 9.6 kbit/s to 115.2 kbit/s)
- Link distance: 30 cm / 20 cm full 15° cone with standard or low power IrDA, respectively. Emission intensity can be set by an external resistor to increase the range to > 50 cm
- Typical transmission distance to standard device: 50 cm
- Small package (L x W x H in mm): 6.8 x 2.8 x 1.6
- Low current consumption 75 μ A idle at 3.6 V
- Operates from 2.4 V to 5.5 V within specification over full temperature range from -30 °C to +85 °C
- Split power supply, emitter can be driven by a separate power supply not loading the regulated. U.S. pat. no. 6,157,476
- Adjustable to logic I/O voltage swing from 1.5 V to 5.5 V
- Qualified for lead (Pb)-free and Sn/Pb processing (MSL4)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

ADDITIONAL RESOURCES



DESCRIPTION

The TFBS4652 is one of the smallest IrDA® compliant transceivers available. It supports data rates up to 115 kbit/s. The transceiver consists of a PIN photodiode, infrared emitter, and control IC in a single package.

APPLICATIONS

- Mobile phone
- PDAs

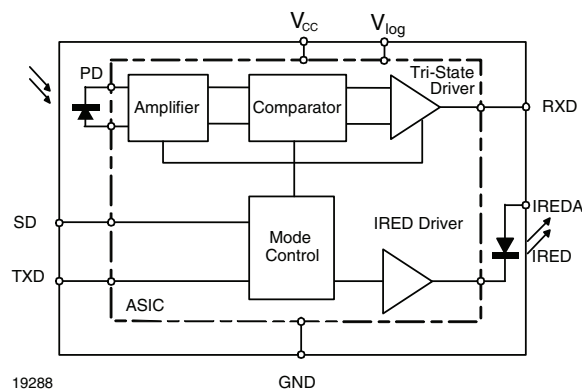
PRODUCT SUMMARY

PART NUMBER	DATA RATE (kbit/s)	DIMENSIONS H x L x W (mm x mm x mm)	LINK DISTANCE (m)	OPERATING VOLTAGE (V)	IDLE SUPPLY CURRENT (mA)
TFBS4652	115.2	1.6 x 6.8 x 2.8	0 to \geq 0.3	2.4 to 5.5	0.075

PARTS TABLE

PART	DESCRIPTION	QTY/REEL
TFBS4652-TR1	Oriented in carrier tape for side view surface mounting	1000 pcs
TFBS4652-TR3	Oriented in carrier tape for side view surface mounting	2500 pcs
TFBS4652-TT1	Oriented in carrier tape for top view surface mounting	1000 pcs

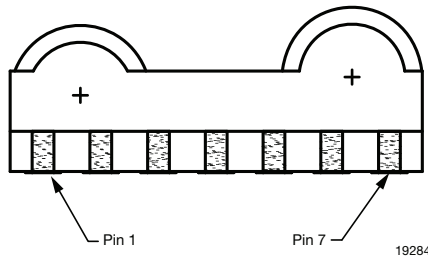
FUNCTIONAL BLOCK DIAGRAM



PIN DESCRIPTION				
PIN NUMBER	SYMBOL	DESCRIPTION	I/O	ACTIVE
1	IREDA	IREDA anode, connected via a current limiting resistor to V_{CC2} . A separate unregulated power supply can be used.		
2	RXD	Receiver output. Normally high, goes low for a defined pulse duration with the rising edge of the optical input signal. Output is a CMOS tri-state driver, which swings between ground and V_{logic} . Receiver echoes transmitter output.	O	Low
3	TXD	Transmitter data input. Setting this input above the threshold turns on the transmitter. This input switches the IRED with the maximum transmit pulse width of about 100 μ s.	I	High
4	SD	Shutdown. Logic low at this input enables the receiver, enables the transmitter, and un-tri-states the receiver output. It must be driven high for shutting down the transceiver.	I	High
5	V_{logic}	Reference for the logic swing of the output and the input logic levels.	I	
6	V_{CC}	Power supply, 2.4 V to 5.5 V. This pin provides power for the receiver and transmitter drive section. Connect V_{CC1} via an optional filter.		
7	GND	Ground		

PINOUT

TFBS4652, bottom view
weight 0.05 g


Definitions:

In the Vishay transceiver datasheets the following nomenclature is used for defining the IrDA operating modes:

- SIR: 2.4 kbit/s to 115.2 kbit/s, equivalent to the basic serial infrared standard with the physical layer version IrPhy 1.0
- MIR: 576 kbit/s to 1152 kbit/s
- FIR: 4 Mbit/s
- VFIR: 16 Mbit/s

MIR and FIR were implemented with IrPhy 1.1, followed by IrPhy 1.2, adding the SIR Low Power Standard. IrPhy 1.3 extended the low power option to MIR and FIR and VFIR was added with IrPhy 1.4. A new version of the standard in any case obsoletes the former version.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply voltage range, transceiver	$0\text{ V} < V_{CC2} < 6\text{ V}$	V_{CC1}	-0.5	-	6	V
Supply voltage range, transmitter	$0\text{ V} < V_{CC1} < 6\text{ V}$	V_{CC2}	-0.5	-	6	V
Supply voltage range, digital supply	$0\text{ V} < V_{CC1} < 6\text{ V}$	V_{logic}	-0.5	-	6	V
Voltage at RXD	All states	V_{IN}	-0.5	-	$V_{logic} + 0.5$	V
Input voltage range, transmitter TXD	Independent of V_{dd} or V_{logic}	V_{IN}	-0.5	-	6	V
Input currents	For all pins, except IRED anode pin		-40	-	40	mA
Output sinking current			-	-	20	mA
Power dissipation		P_D	-	-	250	mW
Junction temperature		T_J	-	-	125	$^{\circ}\text{C}$
Ambient temperature range (operating)		T_{amb}	-30	-	+85	$^{\circ}\text{C}$
Storage temperature		T_{stg}	-40	-	+100	$^{\circ}\text{C}$
Soldering temperature ⁽¹⁾	See section "Recommended Solder Profile"		-	-	260	$^{\circ}\text{C}$
Repetitive pulse output current	$< 90\ \mu\text{s}$, $t_{on} < 20\%$	$I_{IRED}(\text{RP})$	-	-	500	mA
Average output current (transmitter)		$I_{IRED}(\text{DC})$	-	-	100	mA
Thermal resistance junction-to-ambient	JESD51	R_{thJA}	-	300	-	K/W

Notes

- Reference point pin, GND unless otherwise noted
Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- ⁽¹⁾ Sn/lead (Pb)-free soldering. The product passed Vishay's standard convection reflow profile soldering test



EYE SAFETY INFORMATION	
STANDARD	CLASSIFICATION
IEC/EN 60825-1 (2007-03), DIN EN 60825-1 (2008-05) "SAFETY OF LASER PRODUCTS - Part 1: equipment classification and requirements", simplified method	Class 1
IEC 62471 (2006), CIE S009 (2002) "Photobiological Safety of Lamps and Lamp Systems"	Exempt
DIRECTIVE 2006/25/EC OF THE EUROPEAN PARLIAMENT AND OF THE COUNCIL of 5 th April 2006 on the minimum health and safety requirements regarding the exposure of workers to risks arising from physical agents (artificial optical radiation) (19 th individual directive within the meaning of article 16(1) of directive 89/391/EEC)	Exempt

Note

- Vishay transceivers operating inside the absolute maximum ratings are classified as eye safe according the above table

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, V _{CC} = 2.4 V to 5.5 V unless otherwise noted)						
PARAMETER	TEST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
TRANSCEIVER						
Supply voltage range		V _{CC}	2.4	-	5.5	V
Dynamic supply current						
Idle, dark ambient	SD = low (< 0.8 V), E _{eamb} = 0 klx, E _e < 4 mW/m ² , -25 °C ≤ T ≤ +85 °C	I _{CC}	-	90	130	μA
Idle, dark ambient	SD = low (< 0.8 V), E _{eamb} = 0 klx, E _e < 4 mW/m ² , T = +25 °C	I _{CC}	-	75	-	μA
Peak supply current during transmission	SD = low, TXD = high	I _{CCPK}	-	2	3	mA
Idle, dark ambient at V _{logic} - pin	SD = low (< 0.8 V), E _{eamb} = 0 klx, E _e < 4 mW/m ²	I _{logic}	-	-	1	μA
Shutdown supply current, dark ambient	SD = high (> V _{logic} - 0.5 V), T = 25 °C, E _e = 0 klx	I _{SD}	-	-	0.1	μA
	SD = high (> V _{logic} - 0.5 V), T = 70 °C, E _e = 0 klx	I _{SD}	-	-	2	μA
	SD = high (> V _{logic} - 0.5 V), T = 85 °C, E _e = 0 klx	I _{SD}	-	-	3	μA
Operating temperature range		T _{amb}	-30	-	+85	°C
Output voltage low	I _{OL} = 0.2 mA, V _{CC} = 2.4 V, C _{load} = 15 pF	V _{OL}	-	0.3	-	V
Output voltage high	I _{OL} = 0.2 mA, V _{CC} = 2.4 V, C _{load} = 15 pF	V _{OH}	V _{logic} - 0.5	-	V _{logic}	V
RXD to V _{logic} pull-up impedance	SD = high (> V _{logic} - 0.5 V)	R _{RXD}	-	500	-	kΩ
Input voltage low (TXD, SD)		V _{IL}	-0.5	-	0.5	V
Input voltage high (TXD, SD)	V _{CC} = 2.4 V to 5.5 V	V _{IH}	V _{logic} - 0.5	-	6	V
Input voltage threshold SD	V _{CC} = 2.4 V to 5.5 V		0.9	0.5 x V _{logic}	0.66 x V _{logic}	V
Input capacitance (TXD, SD)		C _I	-	-	6	pF

Note

- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing



OPTOELECTRONIC CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
RECEIVER						
Sensitivity: minimum irradiance E_e in angular range ⁽¹⁾⁽²⁾	9.6 kbit/s to 115.2 kbit/s $\lambda = 850 \text{ nm to } 900 \text{ nm}$	E_e	-	40 (4)	81 (8.1)	mW/m^2 ($\mu\text{W/cm}^2$)
Maximum irradiance E_e in angular range ⁽³⁾	$\lambda = 850 \text{ nm to } 900 \text{ nm}$	E_e	5 (500)	-	-	kW/m^2 (mW/cm^2)
No output receiver input irradiance	According to IrDA IrPHY 1.4, appendix A1, fluorescent light specification	E_e	4 (0.4)	-	-	mW/m^2 ($\mu\text{W/cm}^2$)
Rise time of output signal	10 % to 90 %, $C_L = 15 \text{ pF}$	$t_{r(RXD)}$	20	-	100	ns
Fall time of output signal	90 % to 10 %, $C_L = 15 \text{ pF}$	$t_{f(RXD)}$	20	-	100	ns
RXD pulse width of output signal, 50 % ⁽⁴⁾	Input pulse width 1.63 μs	t_{PW}	1.7	-	2.9	μs
Receiver start up time	Power on delay		-	100	150	μs
Latency		t_L	30	50	100	μs
TRANSMITTER						
IRED operating current, current controlled	The IRED current is internally controlled but also can be reduced by an external resistor R1	I_D	200	300	400	mA
Forward voltage of built-in IRED	$I_F = 300 \text{ mA}$	V_F	1.4	1.8	1.9	V
Output leakage IRED current	$T_{amb} = 85^\circ\text{C}$	I_{IRED}	-	-	1	μA
Output radiant intensity ⁽⁵⁾	$a = 0^\circ, 15^\circ$, TXD = high, SD = low, $V_{CC1} = 3 \text{ V}$, $V_{CC2} = 3 \text{ V}$, $R1 = 30 \Omega$ (resulting in about 50 mA drive current)	I_e	5	10	25	mW/sr
Output radiant intensity ⁽⁵⁾	$a = 0^\circ, 15^\circ$, TXD = high, SD = low, $V_{CC1} = 3 \text{ V}$, $V_{CC2} = 3 \text{ V}$, $R1 = 0 \Omega$, $I_F = 300 \text{ mA}$	I_e	30	65	150	mW/sr
Output radiant intensity ⁽⁵⁾	$V_{CC1} = 5 \text{ V}$, $a = 0^\circ, 15^\circ$ TXD = low or SD = high (receiver is inactive as long as SD = high)	I_e	-	-	0.0.4	mW/sr
Saturation voltage of IRED driver	$V_{CC} = 3 \text{ V}$, $I_F = 50 \text{ mA}$	V_{CESat}	-	0.4	-	V
Peak - emission wavelength		λ_p	880	886	-	nm
Spectral bandwidth		$\Delta\lambda$	-	45	-	nm
Optical rise time, optical fall time		t_{ropt} , t_{fopt}	20	-	100	ns
Optical output pulse duration	Input pulse width $t < 30 \mu\text{s}$ Input pulse width $t \geq 30 \mu\text{s}$	t_{opt} t_{opt}	- 30	t 50	- 300	μs μs
Optical output pulse duration	Input pulse width $t = 1.63 \mu\text{s}$	t_{opt}	1.45	1.61	2.2	μs
Optical overshoot			-	-	20	%

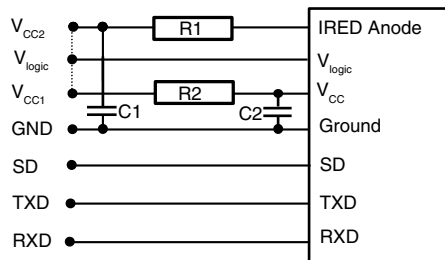
Notes

- $T_{amb} = 25^\circ\text{C}$, $V_{CC} = 2.4 \text{ V to } 5.5 \text{ V}$ unless otherwise noted. Typical values are for design aid only, not guaranteed nor subject to production testing
- This parameter reflects the backlight test of the IrDA physical layer specification to guarantee immunity against light from fluorescent lamps
 - IrDA sensitivity definition: minimum irradiance E_e in angular range, power per unit area. The receiver must meet the BER specification while the source is operating at the minimum intensity in angular range into the minimum half-angular range at the maximum link length
 - Maximum irradiance E_e in angular range, power per unit area. The optical delivered to the detector by a source operating at the maximum intensity in angular range at minimum link length must not cause receiver overdrive distortion and possible related link errors. If placed at the active output interface reference plane of the transmitter, the receiver must meet its bit error ratio (BER) specification. For more definitions see the document "Symbols and Terminology" on the Vishay website
 - RXD output is edge triggered by the rising edge of the optical input signal. The output pulse duration is independent of the input pulse duration
 - The radiant intensity can be adjusted by the external current limiting resistor to adapt the intensity to the desired value. The given value is for minimum current consumption. This transceiver can be adapted to > 50 cm operation by increasing the current to > 200 mA, e.g. operating the transceiver without current control resistor (i.e. $R1 = 0 \Omega$) and using the internal current control

TRUTH TABLE				
INPUTS			OUTPUTS	
SD	TXD	OPTICAL INPUT IRRADIANCE mW/m ²	RXD	TRANSMITTER
High	x	x	Tri-state floating with a weak pull-up to the supply voltage	0
Low	High	x	Low (echo on)	I _e
Low	High > 100 μs	x	High	0
Low	Low	< 2	High	0
Low	Low	> min. irradiance E _e < max. irradiance E _e	Low (active)	0
Low	Low	> max. irradiance E _e	x	0

RECOMMENDED CIRCUIT DIAGRAM

Operated at a clean low impedance power supply the TFBS4652 needs only one additional external component when the IRED drive current should be minimized for minimum current consumption according the low power IrDA standard. When combined operation in IrDA and remote control is intended no current limiting resistor is recommended. When long wires are used for bench tests, the capacitors are mandatory for testing rise/fall time correctly.



19289

Fig. 1 - Recommended Application Circuit

The capacitor C1 is buffering the supply voltage V_{CC2} and eliminates the inductance of the power supply line. This one should be a small ceramic version or other fast capacitor to guarantee the fast rise time of the IRED current. The resistor R1 is necessary for controlling the IRED drive current when the internally controlled current is too high for the application.

Vishay transceivers integrate a sensitive receiver and a built-in power driver. The combination of both needs a careful circuit board layout. The use of thin, long, resistive and inductive wiring should be avoided. The inputs (TXD, SD) and the output RXD should be directly (DC) coupled to the I/O circuit.

The capacitor C2 combined with the resistor R2 is the low pass filter for smoothing the supply voltage.

As already stated above R2, C1 and C2 are optional and depend on the quality of the supply voltages V_{CCx} and injected noise. An unstable power supply with dropping voltage during transmission may reduce the sensitivity (and

transmission range) of the transceiver.

The placement of these parts is critical. It is strongly recommended to position C2 as close as possible to the transceiver power supply pins.

When connecting the described circuit to the power supply, low impedance wiring should be used.

In case of extended wiring the inductance of the power supply can cause dynamically a voltage drop at V_{CC2}. Often some power supplies are not apply to follow the fast current is rise time. In that case another 10 μF cap at V_{CC2} will be helpful.

Keep in mind that basic RF-design rules for circuit design should be taken into account. Especially longer signal lines should not be used without termination. See e.g. "The Art of Electronics" Paul Horowitz, Wienfield Hill, 1989, Cambridge University Press, ISBN: 0521370957.

RECOMMENDED APPLICATION CIRCUIT COMPONENTS

COMPONENT	RECOMMENDED VALUE
C1, C2	0.1 μF, ceramic Vishay part# VJ 1206 Y 104 J XXMT
R1	See table below
R2	47 Ω, 0.125 W (V _{CC1} = 3 V)

RECOMMENDED RESISTOR R1 (Ω)

V _{CC2} (V)	MINIMIZED CURRENT CONSUMPTION, IrDA LOW POWER COMPLIANT
2.7	24
3	30
3.3	36

RECOMMENDED SOLDER PROFILES

Solder Profile for Sn/Pb Soldering

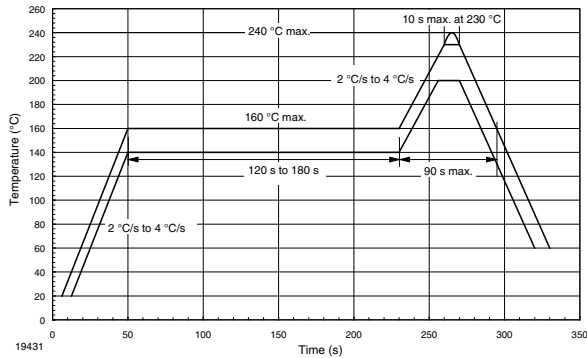


Fig. 2 - Recommended Solder Profile for Sn/Pb Soldering

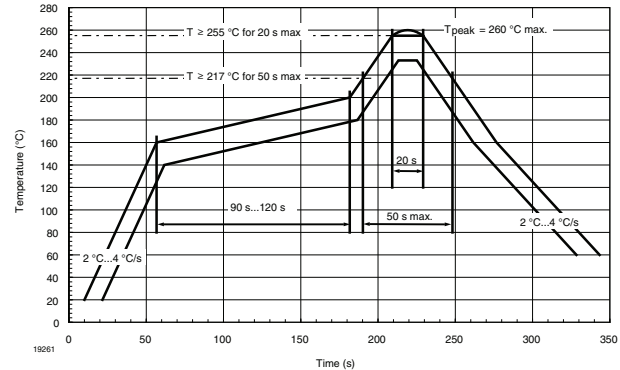


Fig. 3 - Solder Profile, RSS Recommendation

Lead (Pb)-Free, Recommended Solder Profile

The TFBS4652 is a lead (Pb)-free transceiver and qualified for lead (Pb)-free processing. For lead (Pb)-free solder paste like Sn_(3.0 - 4.0)Ag_(0.5 - 0.9)Cu, there are two standard reflow profiles: Ramp-Soak-Spike (RSS) and Ramp-To-Spike (RTS). The Ramp-Soak-Spike profile was developed primarily for reflow ovens heated by infrared radiation. With widespread use of forced convection reflow ovens the Ramp-To-Spike profile is used increasingly. Shown in figure 2 is Vishay’s recommended profiles for use with the TFBS4652 transceivers. For more details please refer to the application note “SMD Assembly Instructions”.

Wave Soldering

For TFDUxxxx, TFBSxxxx, and TFBRxxxx transceiver devices wave soldering is not recommended.

Manual Soldering

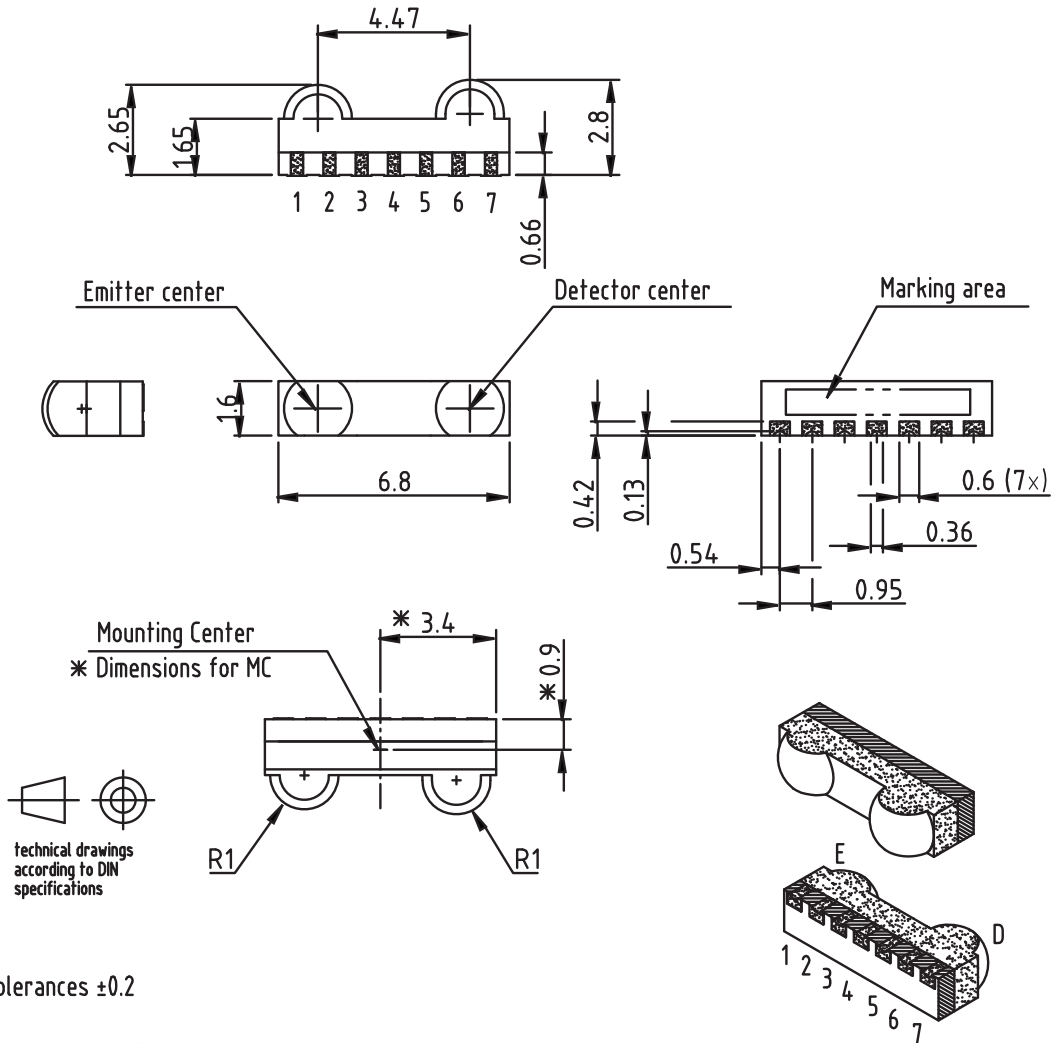
Manual soldering is the standard method for lab use. However, for a production process it cannot be recommended because the risk of damage is highly dependent on the experience of the operator. Nevertheless, we added a chapter to the above mentioned application note, describing manual soldering and desoldering.

Storage

The storage and drying processes for all Vishay transceivers (TFDUxxxx, TFBSxxxx, and TFBRxxxx) are equivalent to MSL4.

The data for the drying procedure is given on labels on the packing and also in the application note “Taping, Labeling, Storage and Packing”.

PACKAGE DIMENSIONS in millimeters



Tolerances ± 0.2

Drawing-No.: 6.550-5268.01-4

Issue: 2; 06.03.06

19322

Fig. 4 - TFBS4650 Mechanical Dimensions, Tolerance ± 0.2 mm, if not otherwise mentioned

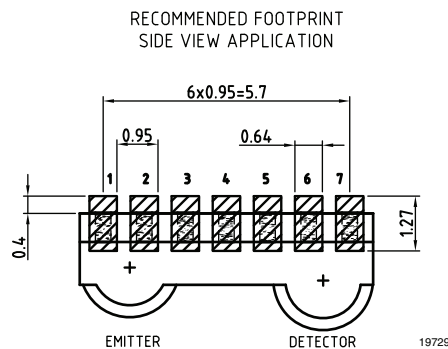
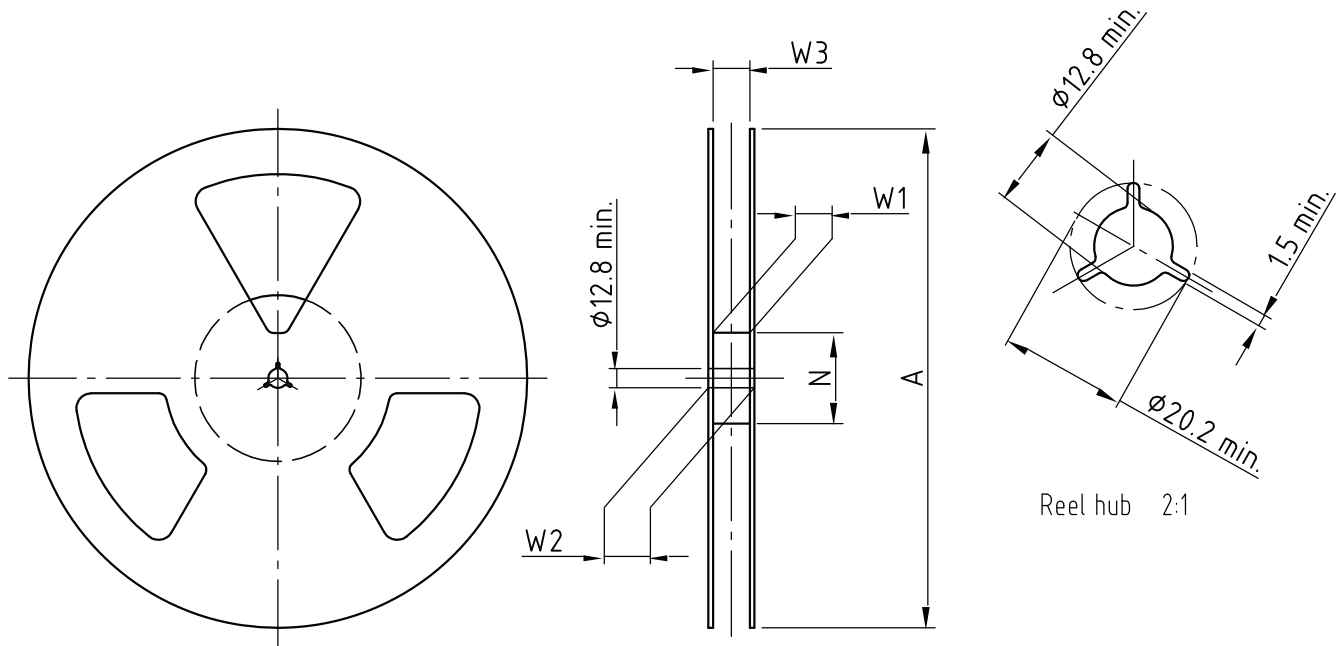


Fig. 5 - TFBS4650 Soldering Footprint, Tolerance ± 0.2 mm, if not otherwise mentioned

REEL DIMENSIONS in millimeters

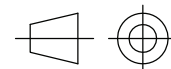


Drawing-No.: 9.800-5090.01-4
Issue: 1; 29.11.05

14017

Form of the leave open of the wheel is supplier specific.

Dimension acc. to IEC EN 60 286-3

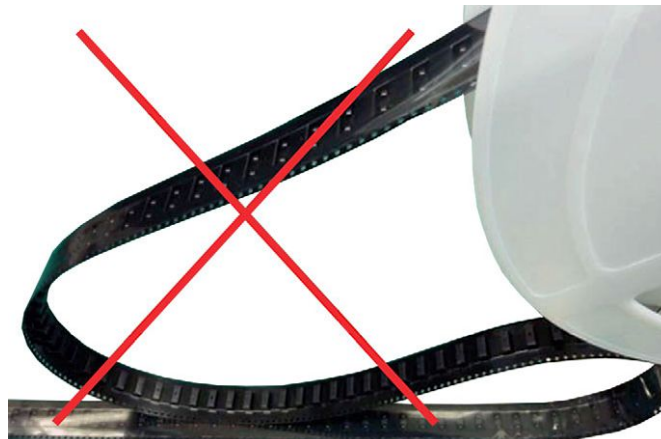


technical drawings according to DIN specifications

TAPE WIDTH (mm)	A MAX. (mm)	N (mm)	W ₁ MIN. (mm)	W ₂ MAX. (mm)	W ₃ MIN. (mm)	W ₃ MAX. (mm)
16	180	60	16.4	22.4	15.9	19.4
16	330	50	16.4	22.4	15.9	19.4

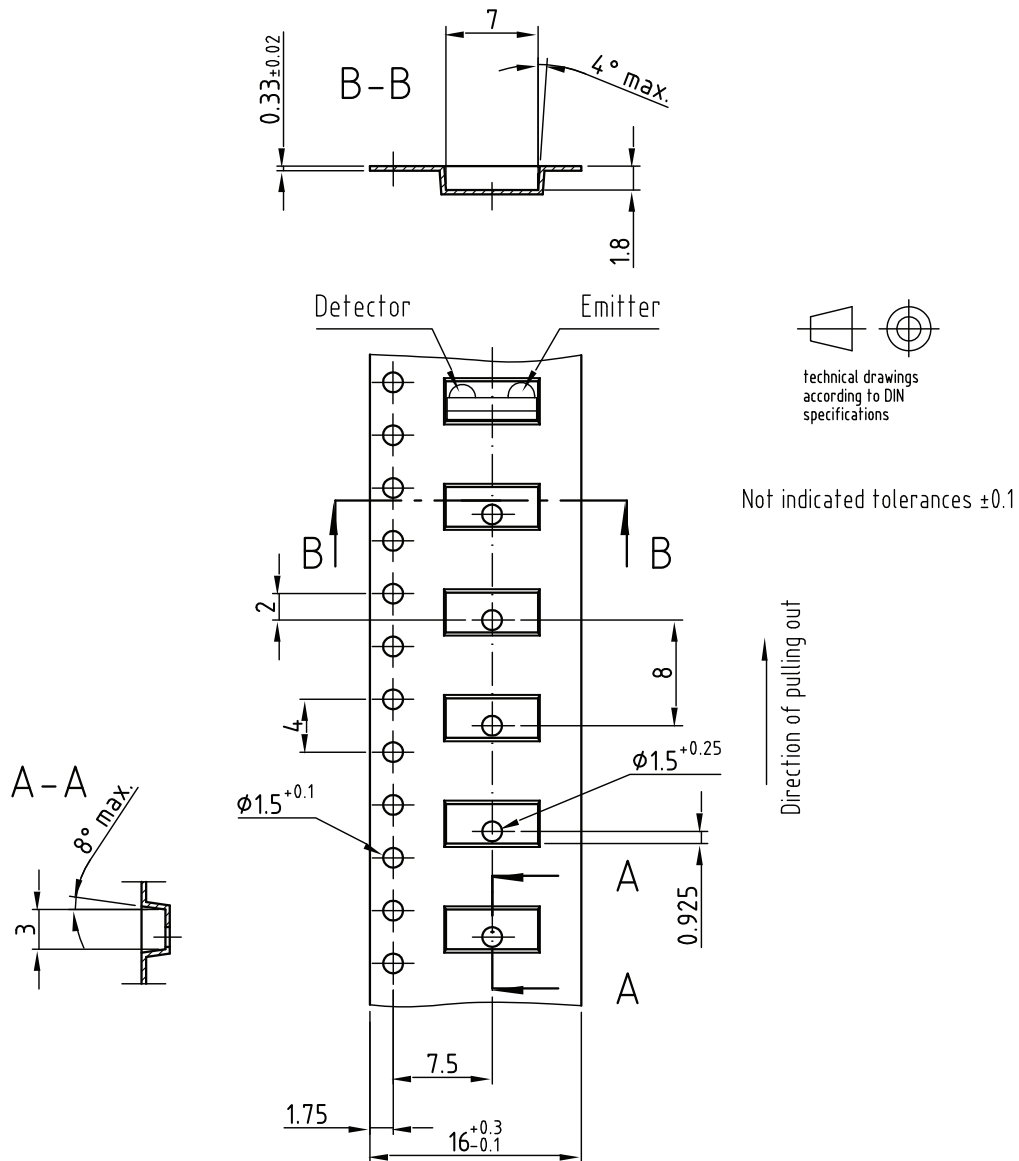
HANDLING PRECAUTION

Sagging of carrier tape may cause some units to rotate and will result to pick-and-place problem. Do not allow carrier tape to sag as shown in picture below.



TAPE DIMENSIONS FOR TR1 AND TR3 in millimeters

Tape for Side View Oriented Parts



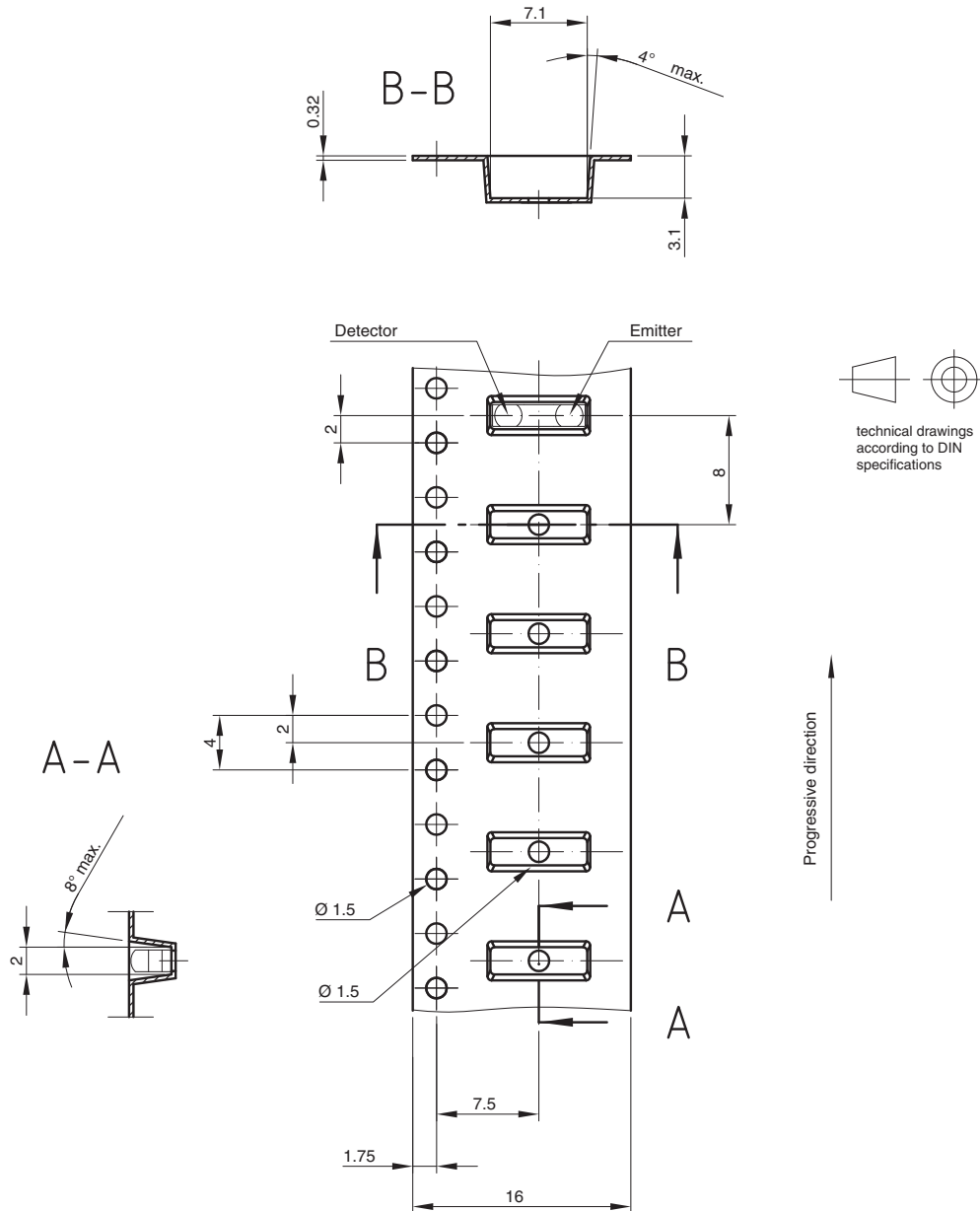
Drawing-No.: 9.700-5296.01-4

Issue: prel. copy; 24.11.04

19285

TAPE DIMENSIONS FOR TT1 in millimeters

Tape for Top View Oriented Parts



Drawing-No.: 9.700-5340.01-4
 Issue: 1; 15.01.09
 21663



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